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Altera - EPF10K200SBC600-2 Datasheet



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	470
Number of Gates	-
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	600-BGA
Supplier Device Package	600-BGA (45x45)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=epf10k200sbc600-2

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- Software design support and automatic place-and-route provided by Altera's development systems for Windows-based PCs and Sun SPARCstation, and HP 9000 Series 700/800
- Flexible package options
 - Available in a variety of packages with 144 to 672 pins, including the innovative FineLine BGA[™] packages (see Tables 3 and 4)
 - SameFrame[™] pin-out compatibility between FLEX 10KA and FLEX 10KE devices across a range of device densities and pin counts
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), DesignWare components, Verilog HDL, VHDL, and other interfaces to popular EDA tools from manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, VeriBest, and Viewlogic

Table 3. FLEX 10KE Package Options & I/O Pin Count Notes (1), (2)											
Device	144-Pin TQFP	208-Pin PQFP	240-Pin PQFP RQFP	256-Pin FineLine BGA	356-Pin BGA	484-Pin FineLine BGA	599-Pin PGA	600-Pin BGA	672-Pin FineLine BGA		
EPF10K30E	102	147		176		220			220 (3)		
EPF10K50E	102	147	189	191		254			254 (3)		
EPF10K50S	102	147	189	191	220	254			254 (3)		
EPF10K100E		147	189	191	274	338			338 (3)		
EPF10K130E			186		274	369		424	413		
EPF10K200E							470	470	470		
EPF10K200S			182		274	369	470	470	470		

Notes:

- (1) FLEX 10KE device package types include thin quad flat pack (TQFP), plastic quad flat pack (PQFP), power quad flat pack (RQFP), pin-grid array (PGA), and ball-grid array (BGA) packages.
- (2) Devices in the same package are pin-compatible, although some devices have more I/O pins than others. When planning device migration, use the I/O pins that are common to all devices.
- (3) This option is supported with a 484-pin FineLine BGA package. By using SameFrame pin migration, all FineLine BGA packages are pin-compatible. For example, a board can be designed to support 256-pin, 484-pin, and 672-pin FineLine BGA packages. The Altera software automatically avoids conflicting pins when future migration is set.

Table 4. FLEX 10KE Package Sizes										
Device	144- Pin TQFP	208-Pin PQFP	240-Pin PQFP RQFP	256-Pin FineLine BGA	356- Pin BGA	484-Pin FineLine BGA	599-Pin PGA	600- Pin BGA	672-Pin FineLine BGA	
Pitch (mm)	0.50	0.50	0.50	1.0	1.27	1.0	-	1.27	1.0	
Area (mm ²)	484	936	1,197	289	1,225	529	3,904	2,025	729	
$\begin{array}{l} \text{Length} \times \text{width} \\ \text{(mm} \times \text{mm)} \end{array}$	22 × 22	30.6 × 30.6	34.6×34.6	17 × 17	35×35	23 × 23	62.5 × 62.5	45×45	27 × 27	

General Description

Altera FLEX 10KE devices are enhanced versions of FLEX 10K devices. Based on reconfigurable CMOS SRAM elements, the FLEX architecture incorporates all features necessary to implement common gate array megafunctions. With up to 200,000 typical gates, FLEX 10KE devices provide the density, speed, and features to integrate entire systems, including multiple 32-bit buses, into a single device.

The ability to reconfigure FLEX 10KE devices enables 100% testing prior to shipment and allows the designer to focus on simulation and design verification. FLEX 10KE reconfigurability eliminates inventory management for gate array designs and generation of test vectors for fault coverage.

Table 5 shows FLEX 10KE performance for some common designs. All performance values were obtained with Synopsys DesignWare or LPM functions. Special design techniques are not required to implement the applications; the designer simply infers or instantiates a function in a Verilog HDL, VHDL, Altera Hardware Description Language (AHDL), or schematic design file.

The EAB can also use Altera megafunctions to implement dual-port RAM applications where both ports can read or write, as shown in Figure 3.



The FLEX 10KE EAB can be used in a single-port mode, which is useful for backward-compatibility with FLEX 10K designs (see Figure 4).



Figure 4. FLEX 10KE Device in Single-Port RAM Mode

Note:

(1) EPF10K30E, EPF10K50E, and EPF10K50S devices have 88 EAB local interconnect channels; EPF10K100E, EPF10K130E, EPF10K200E, and EPF10K200S devices have 104 EAB local interconnect channels.

EABs can be used to implement synchronous RAM, which is easier to use than asynchronous RAM. A circuit using asynchronous RAM must generate the RAM write enable signal, while ensuring that its data and address signals meet setup and hold time specifications relative to the write enable signal. In contrast, the EAB's synchronous RAM generates its own write enable signal and is self-timed with respect to the input or write clock. A circuit using the EAB's self-timed RAM must only meet the setup and hold time specifications of the global clock. EABs provide flexible options for driving and controlling clock signals. Different clocks and clock enables can be used for reading and writing to the EAB. Registers can be independently inserted on the data input, EAB output, write address, write enable signals, read address, and read enable signals. The global signals and the EAB local interconnect can drive write enable, read enable, and clock enable signals. The global signals, dedicated clock pins, and EAB local interconnect can drive the EAB clock signals. Because the LEs drive the EAB local interconnect, the LEs can control write enable, read enable, clear, clock, and clock enable signals.

An EAB is fed by a row interconnect and can drive out to row and column interconnects. Each EAB output can drive up to two row channels and up to two column channels; the unused row channel can be driven by other LEs. This feature increases the routing resources available for EAB outputs (see Figures 2 and 4). The column interconnect, which is adjacent to the EAB, has twice as many channels as other columns in the device.

Logic Array Block

An LAB consists of eight LEs, their associated carry and cascade chains, LAB control signals, and the LAB local interconnect. The LAB provides the coarse-grained structure to the FLEX 10KE architecture, facilitating efficient routing with optimum device utilization and high performance (see Figure 7).

Each LAB provides four control signals with programmable inversion that can be used in all eight LEs. Two of these signals can be used as clocks, the other two can be used for clear/preset control. The LAB clocks can be driven by the dedicated clock input pins, global signals, I/O signals, or internal signals via the LAB local interconnect. The LAB preset and clear control signals can be driven by the global signals, I/O signals, or internal signals via the LAB local interconnect. The global control signals are typically used for global clock, clear, or preset signals because they provide asynchronous control with very low skew across the device. If logic is required on a control signal, it can be generated in one or more LE in any LAB and driven into the local interconnect of the target LAB. In addition, the global control signals can be generated from LE outputs.

Logic Element

The LE, the smallest unit of logic in the FLEX 10KE architecture, has a compact size that provides efficient logic utilization. Each LE contains a four-input LUT, which is a function generator that can quickly compute any function of four variables. In addition, each LE contains a programmable flipflop with a synchronous clock enable, a carry chain, and a cascade chain. Each LE drives both the local and the FastTrack Interconnect routing structure (see Figure 8).



Normal Mode

The normal mode is suitable for general logic applications and wide decoding functions that can take advantage of a cascade chain. In normal mode, four data inputs from the LAB local interconnect and the carry-in are inputs to a four-input LUT. The Altera Compiler automatically selects the carry-in or the DATA3 signal as one of the inputs to the LUT. The LUT output can be combined with the cascade-in signal to form a cascade chain through the cascade-out signal. Either the register or the LUT can be used to drive both the local interconnect and the FastTrack Interconnect routing structure at the same time.

The LUT and the register in the LE can be used independently (register packing). To support register packing, the LE has two outputs; one drives the local interconnect, and the other drives the FastTrack Interconnect routing structure. The DATA4 signal can drive the register directly, allowing the LUT to compute a function that is independent of the registered signal; a three-input function can be computed in the LUT, and a fourth independent signal can be registered. Alternatively, a four-input function can be generated, and one of the inputs to this function can be used to drive the register. The register in a packed LE can still use the clock enable, clear, and preset signals in the LE. In a packed LE, the register can drive the FastTrack Interconnect routing structure while the LUT drives the local interconnect, or vice versa.

Arithmetic Mode

The arithmetic mode offers 2 three-input LUTs that are ideal for implementing adders, accumulators, and comparators. One LUT computes a three-input function; the other generates a carry output. As shown in Figure 11 on page 22, the first LUT uses the carry-in signal and two data inputs from the LAB local interconnect to generate a combinatorial or registered output. For example, in an adder, this output is the sum of three signals: a, b, and carry-in. The second LUT uses the same three signals to generate a carry-out signal, thereby creating a carry chain. The arithmetic mode also supports simultaneous use of the cascade chain.

Up/Down Counter Mode

The up/down counter mode offers counter enable, clock enable, synchronous up/down control, and data loading options. These control signals are generated by the data inputs from the LAB local interconnect, the carry-in signal, and output feedback from the programmable register. Use 2 three-input LUTs: one generates the counter data, and the other generates the fast carry bit. A 2-to-1 multiplexer provides synchronous loading. Data can also be loaded asynchronously with the clear and preset register control signals without using the LUT resources.

Asynchronous Clear

The flipflop can be cleared by either LABCTRL1 or LABCTRL2. In this mode, the preset signal is tied to VCC to deactivate it.

Asynchronous Preset

An asynchronous preset is implemented as an asynchronous load, or with an asynchronous clear. If DATA3 is tied to VCC, asserting LABCTRL1 asynchronously loads a one into the register. Alternatively, the Altera software can provide preset control by using the clear and inverting the input and output of the register. Inversion control is available for the inputs to both LEs and IOEs. Therefore, if a register is preset by only one of the two LABCTRL signals, the DATA3 input is not needed and can be used for one of the LE operating modes.

Asynchronous Preset & Clear

When implementing asynchronous clear and preset, LABCTRL1 controls the preset and LABCTRL2 controls the clear. DATA3 is tied to VCC, so that asserting LABCTRL1 asynchronously loads a one into the register, effectively presetting the register. Asserting LABCTRL2 clears the register.

Asynchronous Load with Clear

When implementing an asynchronous load in conjunction with the clear, LABCTRL1 implements the asynchronous load of DATA3 by controlling the register preset and clear. LABCTRL2 implements the clear by controlling the register clear; LABCTRL2 does not have to feed the preset circuits.

Asynchronous Load with Preset

When implementing an asynchronous load in conjunction with preset, the Altera software provides preset control by using the clear and inverting the input and output of the register. Asserting LABCTRL2 presets the register, while asserting LABCTRL1 loads the register. The Altera software inverts the signal that drives DATA3 to account for the inversion of the register's output.

Asynchronous Load without Preset or Clear

When implementing an asynchronous load without preset or clear, LABCTRL1 implements the asynchronous load of DATA3 by controlling the register preset and clear.

ClockLock & ClockBoost Features

To support high-speed designs, FLEX 10KE devices offer optional ClockLock and ClockBoost circuitry containing a phase-locked loop (PLL) used to increase design speed and reduce resource usage. The ClockLock circuitry uses a synchronizing PLL that reduces the clock delay and skew within a device. This reduction minimizes clock-to-output and setup times while maintaining zero hold times. The ClockBoost circuitry, which provides a clock multiplier, allows the designer to enhance device area efficiency by resource sharing within the device. The ClockBoost feature allows the designer to distribute a low-speed clock and multiply that clock on-device. Combined, the ClockLock and ClockBoost features provide significant improvements in system performance and bandwidth.

All FLEX 10KE devices, except EPF10K50E and EPF10K200E devices, support ClockLock and ClockBoost circuitry. EPF10K50S and EPF10K200S devices support this circuitry. Devices that support Clock-Lock and ClockBoost circuitry are distinguished with an "X" suffix in the ordering code; for instance, the EPF10K200SFC672-1X device supports this circuit.

The ClockLock and ClockBoost features in FLEX 10KE devices are enabled through the Altera software. External devices are not required to use these features. The output of the ClockLock and ClockBoost circuits is not available at any of the device pins.

The ClockLock and ClockBoost circuitry locks onto the rising edge of the incoming clock. The circuit output can drive the clock inputs of registers only; the generated clock cannot be gated or inverted.

The dedicated clock pin (GCLK1) supplies the clock to the ClockLock and ClockBoost circuitry. When the dedicated clock pin is driving the ClockLock or ClockBoost circuitry, it cannot drive elsewhere in the device.

For designs that require both a multiplied and non-multiplied clock, the clock trace on the board can be connected to the GCLK1 pin. In the Altera software, the GCLK1 pin can feed both the ClockLock and ClockBoost circuitry in the FLEX 10KE device. However, when both circuits are used, the other clock pin cannot be used.

PCI Pull-Up Clamping Diode Option

FLEX 10KE devices have a pull-up clamping diode on every I/O, dedicated input, and dedicated clock pin. PCI clamping diodes clamp the signal to the $V_{\rm CCIO}$ value and are required for 3.3-V PCI compliance. Clamping diodes can also be used to limit overshoot in other systems.

Clamping diodes are controlled on a pin-by-pin basis. When V_{CCIO} is 3.3 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V or 3.3-V signal, but not a 5.0-V signal. When V_{CCIO} is 2.5 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V signal, but not a 3.3-V or 5.0-V signal. Additionally, a clamping diode can be activated for a subset of pins, which would allow a device to bridge between a 3.3-V PCI bus and a 5.0-V device.

Slew-Rate Control

The output buffer in each IOE has an adjustable output slew rate that can be configured for low-noise or high-speed performance. A slower slew rate reduces system noise and adds a maximum delay of 4.3 ns. The fast slew rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew rate pin-by-pin or assign a default slew rate to all pins on a device-wide basis. The slow slew rate setting affects the falling edge of the output.

Open-Drain Output Option

FLEX 10KE devices provide an optional open-drain output (electrically equivalent to open-collector output) for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write enable signals) that can be asserted by any of several devices. It can also provide an additional wired-OR plane.

MultiVolt I/O Interface

The FLEX 10KE device architecture supports the MultiVolt I/O interface feature, which allows FLEX 10KE devices in all packages to interface with systems of differing supply voltages. These devices have one set of V_{CC} pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

Figure 20 shows the timing requirements for the JTAG signals.



Figure 20. FLEX 10KE JTAG Waveforms

Table 18 shows the timing parameters and values for FLEX 10KE devices.

Table 1	Table 18. FLEX 10KE JTAG Timing Parameters & Values										
Symbol	Parameter	Min	Мах	Unit							
t _{JCP}	TCK clock period	100		ns							
t _{JCH}	TCK clock high time	50		ns							
t _{JCL}	TCK clock low time	50		ns							
t _{JPSU}	JTAG port setup time	20		ns							
t _{JPH}	JTAG port hold time	45		ns							
t _{JPCO}	JTAG port clock to output		25	ns							
t _{JPZX}	JTAG port high impedance to valid output		25	ns							
t _{JPXZ}	JTAG port valid output to high impedance		25	ns							
t _{JSSU}	Capture register setup time	20		ns							
t _{JSH}	Capture register hold time	45		ns							
t _{JSCO}	Update register clock to output		35	ns							
t _{JSZX}	Update register high impedance to valid output		35	ns							
t _{JSXZ}	Update register valid output to high impedance		35	ns							

Figure 30. EAB Synchronous Timing Waveforms



EAB Synchronous Write (EAB Output Registers Used)



Tables 31 through 37 show EPF10K30E device internal and external timing parameters.

Table 31. EPF10K30E Device LE Timing Microparameters (Part 1 of 2) Note (1)										
Symbol	-1 Spee	-1 Speed Grade		-2 Speed Grade		d Grade	Unit			
	Min	Max	Min	Max	Min	Max				
t _{LUT}		0.7		0.8		1.1	ns			
t _{CLUT}		0.5		0.6		0.8	ns			
t _{RLUT}		0.6		0.7		1.0	ns			
t _{PACKED}		0.3		0.4		0.5	ns			
t _{EN}		0.6		0.8		1.0	ns			
t _{CICO}		0.1		0.1		0.2	ns			
t _{CGEN}		0.4		0.5		0.7	ns			

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Table 47. EPF10K100E Device EAB Internal Microparameters Note (1)									
Symbol	-1 Spee	ed Grade	-2 Spee	ed Grade	-3 Spee	ed Grade	Unit		
	Min	Max	Min	Max	Min	Мах			
t _{EABDATA1}		1.5		2.0		2.6	ns		
t _{EABDATA1}		0.0		0.0		0.0	ns		
t _{EABWE1}		1.5		2.0		2.6	ns		
t _{EABWE2}		0.3		0.4		0.5	ns		
t _{EABRE1}		0.3		0.4		0.5	ns		
t _{EABRE2}		0.0		0.0		0.0	ns		
t _{EABCLK}		0.0		0.0		0.0	ns		
t _{EABCO}		0.3		0.4		0.5	ns		
t _{EABBYPASS}		0.1		0.1		0.2	ns		
t _{EABSU}	0.8		1.0		1.4		ns		
t _{EABH}	0.1		0.1		0.2		ns		
t _{EABCLR}	0.3		0.4		0.5		ns		
t _{AA}		4.0		5.1		6.6	ns		
t _{WP}	2.7		3.5		4.7		ns		
t _{RP}	1.0		1.3		1.7		ns		
t _{WDSU}	1.0		1.3		1.7		ns		
t _{WDH}	0.2		0.2		0.3		ns		
t _{WASU}	1.6		2.1		2.8		ns		
t _{WAH}	1.6		2.1		2.8		ns		
t _{RASU}	3.0		3.9		5.2		ns		
t _{RAH}	0.1		0.1		0.2		ns		
t _{WO}		1.5		2.0		2.6	ns		
t _{DD}		1.5		2.0		2.6	ns		
t _{EABOUT}		0.2		0.3		0.3	ns		
t _{EABCH}	1.5		2.0		2.5		ns		
t _{EABCL}	2.7		3.5		4.7		ns		

Table 48. EPF10K100E Device EAB Internal Timing Macroparameters (Part 1 of

2)	Note	(1)
-/		· · /

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		5.9		7.6		9.9	ns
t _{EABRCOMB}	5.9		7.6		9.9		ns
t _{EABRCREG}	5.1		6.5		8.5		ns
t _{EABWP}	2.7		3.5		4.7		ns

Table 62. EPF10K200E Device EAB Internal Timing Macroparameters (Part 2 of 2) Note (1)										
Symbol	-1 Spee	-1 Speed Grade		-2 Speed Grade		ed Grade	Unit			
	Min	Max	Min	Max	Min	Max				
t _{EABWCOMB}	6.7		8.1		10.7		ns			
t _{EABWCREG}	6.6		8.0		10.6		ns			
t _{EABDD}		4.0		5.1		6.7	ns			
t _{EABDATACO}		0.8		1.0		1.3	ns			
t _{EABDATASU}	1.3		1.6		2.1		ns			
t _{EABDATAH}	0.0		0.0		0.0		ns			
t _{EABWESU}	0.9		1.1		1.5		ns			
t _{EABWEH}	0.4		0.5		0.6		ns			
t _{EABWDSU}	1.5		1.8		2.4		ns			
t _{EABWDH}	0.0		0.0		0.0		ns			
t _{EABWASU}	3.0		3.6		4.7		ns			
t _{EABWAH}	0.4		0.5		0.7		ns			
t _{EABWO}		3.4		4.4		5.8	ns			

 Table 63. EPF10K200E Device Interconnect Timing Microparameters
 Note (1)

Symbol	-1 Spee	ed Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{DIN2IOE}		4.2		4.6		5.7	ns
t _{DIN2LE}		1.7		1.7		2.0	ns
t _{DIN2DATA}		1.9		2.1		3.0	ns
t _{DCLK2IOE}		2.5		2.9		4.0	ns
t _{DCLK2LE}		1.7		1.7		2.0	ns
t _{SAMELAB}		0.1		0.1		0.2	ns
t _{SAMEROW}		2.3		2.6		3.6	ns
t _{SAMECOLUMN}		2.5		2.7		4.1	ns
t _{DIFFROW}		4.8		5.3		7.7	ns
t _{TWOROWS}		7.1		7.9		11.3	ns
t _{LEPERIPH}		7.0		7.6		9.0	ns
t _{LABCARRY}		0.1		0.1		0.2	ns
t _{LABCASC}		0.9		1.0		1.4	ns

Table 64. EPF10K200E External Timing Parameters Notes (1), (2)										
Symbol	-1 Spee	d Grade	-2 Spee	-2 Speed Grade		d Grade	Unit			
	Min	Max	Min	Max	Min	Max				
t _{DRR}		10.0		12.0		16.0	ns			
t _{INSU}	2.8		3.4		4.4		ns			
t _{INH}	0.0		0.0		0.0		ns			
t _{оитсо}	2.0	4.5	2.0	5.3	2.0	7.8	ns			
t _{PCISU}	3.0		6.2		-		ns			
t _{PCIH}	0.0		0.0		-		ns			
t _{PCICO}	2.0	6.0	2.0	8.9	-	-	ns			

Table 65. EPF10K200E External Bidirectional Timing Parameters Notes (1), (2)

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit			
	Min	Max	Min	Max	Min	Max				
t _{INSUBIDIR}	3.0		4.0		5.5		ns			
t _{INHBIDIR}	0.0		0.0		0.0		ns			
t _{OUTCOBIDIR}	2.0	4.5	2.0	5.3	2.0	7.8	ns			
t _{XZBIDIR}		8.1		9.5		13.0	ns			
tZXBIDIR		8.1		9.5		13.0	ns			

Notes to tables:

(1) All timing parameters are described in Tables 24 through 30 in this data sheet.

(2) These parameters are specified by characterization.

Tables 66 through 79 show EPF10K50S and EPF10K200S device external timing parameters.

Table 66. EPF10	K50S Device	LE Timing N	licroparame	eters (Part 1	of 2) No	ote (1)	
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{LUT}		0.6		0.8		1.1	ns
t _{CLUT}		0.5		0.6		0.8	ns
t _{RLUT}		0.6		0.7		0.9	ns
t _{PACKED}		0.2		0.3		0.4	ns
t _{EN}		0.6		0.7		0.9	ns
t _{CICO}		0.1		0.1		0.1	ns
t _{CGEN}		0.4		0.5		0.6	ns

Table 66. EPF10K50S Device LE Timing Microparameters (Part 2 of 2) Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{CGENR}		0.1		0.1		0.1	ns
t _{CASC}		0.5		0.8		1.0	ns
t _C		0.5		0.6		0.8	ns
t _{CO}		0.6		0.6		0.7	ns
t _{COMB}		0.3		0.4		0.5	ns
t _{SU}	0.5		0.6		0.7		ns
t _H	0.5		0.6		0.8		ns
t _{PRE}		0.4		0.5		0.7	ns
t _{CLR}		0.8		1.0		1.2	ns
t _{CH}	2.0		2.5		3.0		ns
t _{CL}	2.0		2.5		3.0		ns

Table 67. EPF10K50S Device IOE Timing Microparameters Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{IOD}		1.3		1.3		1.9	ns
t _{IOC}		0.3		0.4		0.4	ns
t _{IOCO}		1.7		2.1		2.6	ns
t _{IOCOMB}		0.5		0.6		0.8	ns
t _{IOSU}	0.8		1.0		1.3		ns
t _{IOH}	0.4		0.5		0.6		ns
t _{IOCLR}		0.2		0.2		0.4	ns
t _{OD1}		1.2		1.2		1.9	ns
t _{OD2}		0.7		0.8		1.7	ns
t _{OD3}		2.7		3.0		4.3	ns
t _{XZ}		4.7		5.7		7.5	ns
t _{ZX1}		4.7		5.7		7.5	ns
t _{ZX2}		4.2		5.3		7.3	ns
t _{ZX3}		6.2		7.5		9.9	ns
t _{INREG}		3.5		4.2		5.6	ns
t _{IOFD}		1.1		1.3		1.8	ns
t _{INCOMB}		1.1		1.3		1.8	ns

Table 71. EPF10K50S External Timing Parameters Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{DRR}		8.0		9.5		12.5	ns
t _{INSU} (2)	2.4		2.9		3.9		ns
t _{INH} (2)	0.0		0.0		0.0		ns
t _{OUTCO} (2)	2.0	4.3	2.0	5.2	2.0	7.3	ns
t _{INSU} (3)	2.4		2.9				ns
t _{INH} (3)	0.0		0.0				ns
t _{оитсо} (3)	0.5	3.3	0.5	4.1			ns
t _{PCISU}	2.4		2.9		-		ns
t _{PCIH}	0.0		0.0		-		ns
t _{PCICO}	2.0	6.0	2.0	7.7	_	-	ns

 Table 72. EPF10K50S External Bidirectional Timing Parameters
 Note (1)

Symbol	-1 Spee	ed Grade	-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR} (2)	2.7		3.2		4.3		ns
t _{INHBIDIR} (2)	0.0		0.0		0.0		ns
t _{INHBIDIR} (3)	0.0		0.0		-		ns
t _{INSUBIDIR} (3)	3.7		4.2		-		ns
t _{OUTCOBIDIR} (2)	2.0	4.5	2.0	5.2	2.0	7.3	ns
t _{XZBIDIR} (2)		6.8		7.8		10.1	ns
t _{ZXBIDIR} (2)		6.8		7.8		10.1	ns
t _{outcobidir} (3)	0.5	3.5	0.5	4.2	-	-	
t _{XZBIDIR} (3)		6.8		8.4		-	ns
t _{ZXBIDIR} (3)		6.8		8.4		-	ns

Notes to tables:

(1) All timing parameters are described in Tables 24 through 30.

(2) This parameter is measured without use of the ClockLock or ClockBoost circuits.

(3) This parameter is measured with use of the ClockLock or ClockBoost circuits

To better reflect actual designs, the power model (and the constant K in the power calculation equations) for continuous interconnect FLEX devices assumes that LEs drive FastTrack Interconnect channels. In contrast, the power model of segmented FPGAs assumes that all LEs drive only one short interconnect segment. This assumption may lead to inaccurate results when compared to measured power consumption for actual designs in segmented FPGAs.

Figure 31 shows the relationship between the current and operating frequency of FLEX 10KE devices.



Figure 31. FLEX 10KE I_{CCACTIVE} vs. Operating Frequency (Part 1 of 2)

During initialization, which occurs immediately after configuration, the device resets registers, enables I/O pins, and begins to operate as a logic device. The I/O pins are tri-stated during power-up, and before and during configuration. Together, the configuration and initialization processes are called *command mode*; normal device operation is called *user mode*.

SRAM configuration elements allow FLEX 10KE devices to be reconfigured in-circuit by loading new configuration data into the device. Real-time reconfiguration is performed by forcing the device into command mode with a device pin, loading different configuration data, reinitializing the device, and resuming user-mode operation. The entire reconfiguration process requires less than 85 ms and can be used to reconfigure an entire system dynamically. In-field upgrades can be performed by distributing new configuration files.

Before and during configuration, all I/O pins (except dedicated inputs, clock, or configuration pins) are pulled high by a weak pull-up resistor.

Programming Files

Despite being function- and pin-compatible, FLEX 10KE devices are not programming- or configuration file-compatible with FLEX 10K or FLEX 10KA devices. A design therefore must be recompiled before it is transferred from a FLEX 10K or FLEX 10KA device to an equivalent FLEX 10KE device. This recompilation should be performed both to create a new programming or configuration file and to check design timing in FLEX 10KE devices, which has different timing characteristics than FLEX 10K or FLEX 10KA devices.

FLEX 10KE devices are generally pin-compatible with equivalent FLEX 10KA devices. In some cases, FLEX 10KE devices have fewer I/O pins than the equivalent FLEX 10KA devices. Table 81 shows which FLEX 10KE devices have fewer I/O pins than equivalent FLEX 10KA devices. However, power, ground, JTAG, and configuration pins are the same on FLEX 10KA and FLEX 10KE devices, enabling migration from a FLEX 10KA design to a FLEX 10KE design.

Device Pin-Outs	See the Altera web site (http://www.altera.com) or the Altera Digital Library for pin-out information.					
Revision History	The information contained in the <i>FLEX 10KE Embedded Programmable Logic Data Sheet</i> version 2.5 supersedes information published in previous versions.					
	Version 2.5					
	The following changes were made to the <i>FLEX 10KE Embedded Programmable Logic Data Sheet</i> version 2.5:					
	 <i>Note (1)</i> added to Figure 23. Text added to "I/O Element" section on page 34. Updated Table 22. 					
	Version 2.4					
	The following changes were made to the FLEX 10KE Embedded					

Programmable Logic Data Sheet version 2.4: updated text on page 34 and page 63.